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### February 2013

## **FDMC8321L** N-Channel Power Trench<sup>®</sup> MOSFET 40 V, 49 A, 2.5 m $\Omega$

### Features

- Max  $r_{DS(on)}$  = 2.5 m $\Omega$  at  $V_{GS}$  = 10 V,  $I_D$  = 22 A
- Max  $r_{DS(on)}$  = 4.1 m $\Omega$  at V<sub>GS</sub> = 4.5 V, I<sub>D</sub> = 18 A
- Advanced Package and Silicon combination for low r<sub>DS(on)</sub> and hign efficiency
- Next Generation enhanced body diode technology, engineered for soft recovery
- 100% UIL tested
- RoHS Compliant

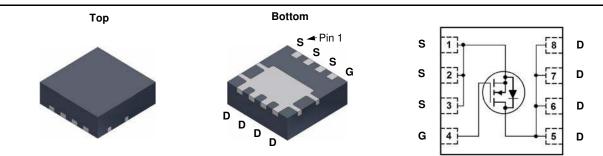


### **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or convertional switching PWM contollers. It has been optimized for low gate charge, low  $r_{DS(on)}$ , fast switching speed body diode reverse recovery performance.

### Applications

- Synchronous rectifier
- Load switch/Orring
- Motor switch



Power 33

### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage			40	V		
V <sub>GS</sub>	Gate to Source V	/oltage			±20	V	
	Drain Current	-Continuous	T <sub>C</sub> = 25 °C		49		
I <sub>D</sub>		-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	22	Α	
		-Pulsed			100		
E <sub>AS</sub>	Single Pulse Ava	lanche Energy		(Note 3)	86	mJ	
P <sub>D</sub>	Power Dissipatio	Power Dissipation			40	w	
	Power Dissipation	n	T <sub>A</sub> = 25 °C	(Note 1a)	2.3	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range				-55 to +150	°C	

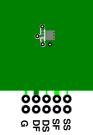
### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	3.1	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	53	0/00

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC8321L	FDMC8321L	Power33	13 "	12 mm	3000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	40			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		22		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 32 V, V_{GS} = 0 V$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-5	0	mV/°C
r <sub>DS(on)</sub>		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 22 \text{ A}$		1.9	2.5	-
	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 18 \text{ A}$		2.7 4.1 m		mΩ
· · /		$V_{GS}$ = 10 V, I <sub>D</sub> = 22 A, T <sub>J</sub> = 125 °C		2.8	3.7	1
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5 \text{ V}, \ I_D = 22 \text{ A}$		114		S
C <sub>iss</sub>	Characteristics Input Capacitance Output Capacitance	- V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V,		2930	3900 1330	pF
C <sub>oss</sub>	Output Capacitance	f = 1 MHz		1000 60	90	pF
C <sub>rss</sub> R <sub>g</sub>	Reverse Transfer Capacitance Gate Resistance		0.1	0.7	2.5	pF Ω
			0.1	0.7	2.5	32
	Characteristics			10		
t <sub>d(on)</sub>	Turn-On Delay Time			12	22	ns
t <sub>r</sub>	Rise Time	$V_{DD} = 20 V, I_D = 22 A,$		6.1	12	ns
t <sub>d(off)</sub>	Turn-Off Delay Time Fall Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		32 4.9	51 10	ns
t <sub>f</sub>	Total Gate Charge at 10 V			4.9	61	ns nC
Q <sub>g(TOT)</sub>	Total Gate Charge at 5 V			21	32	nC
Q <sub>g(TOT)</sub> Q <sub>gs</sub>	Total Gate Charge	– V <sub>DD</sub> = 20 V, I <sub>D</sub> = 22 A		7.7	52	nC
∝ <sub>gs</sub> Q <sub>gd</sub>	Gate to Drain "Miller" Charge			5.8		nC
-	urce Diode Characteristics					
Drain-Sol		$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.69	1.2	<u> </u>
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 22 A$ (Note 2) $V_{GS} = 0 V, I_S = 22 A$ (Note 2)		0.03	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0.0, r_S = 22.4$ (Note 2) - $I_F = 22.4$ , di/dt = 100 A/µs		41	65	ns
Q <sub>rr</sub>	Reverse Recovery Charge			20	33	nC
otes:	interest in the second standard			•		



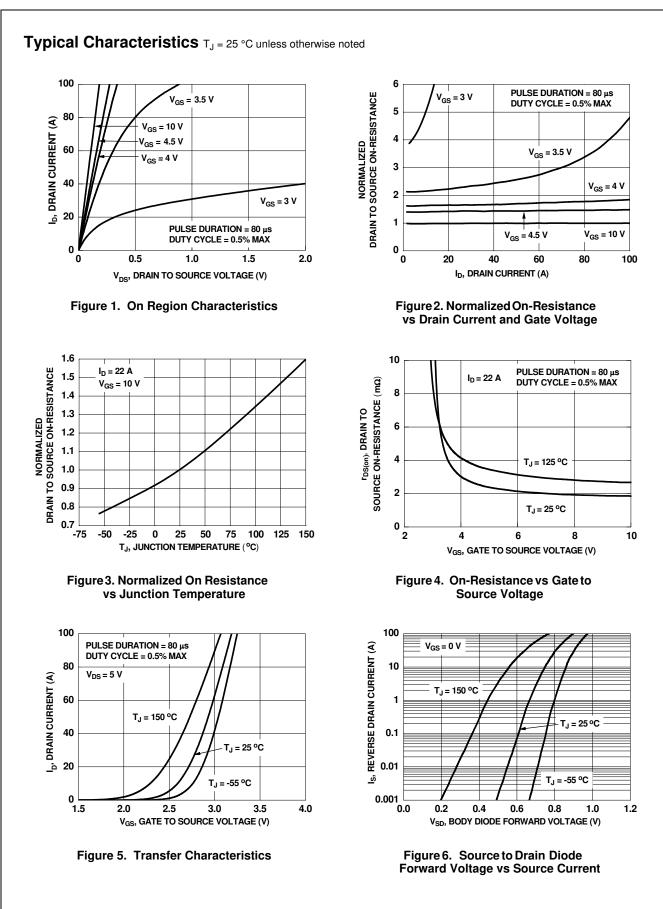
3.Starting T\_J = 25 °C; N-ch: L = 0.3 mH, I\_{AS} = 24 A, V\_DD = 36 V, V\_{GS} = 10 V.

2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

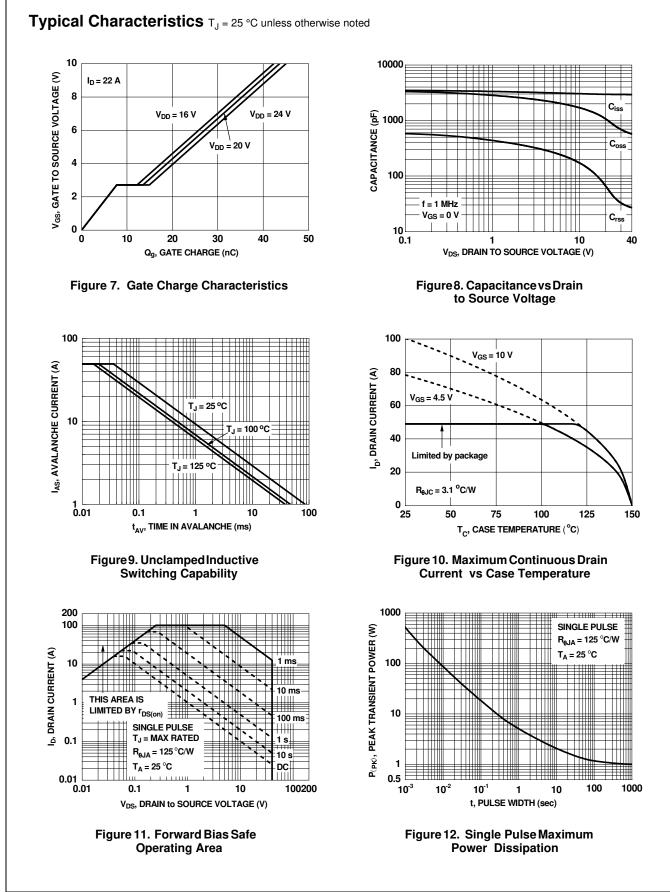
53 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper

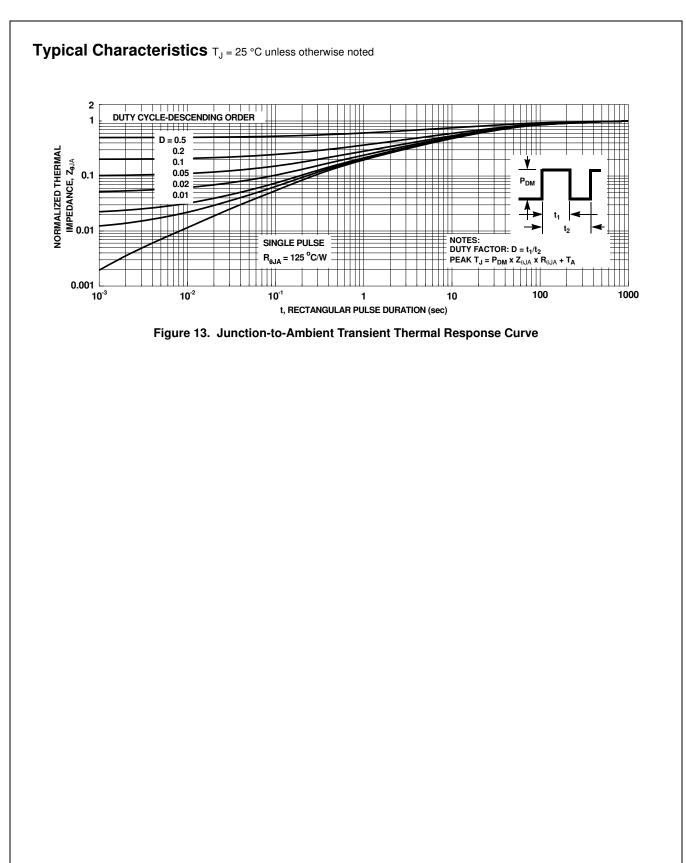


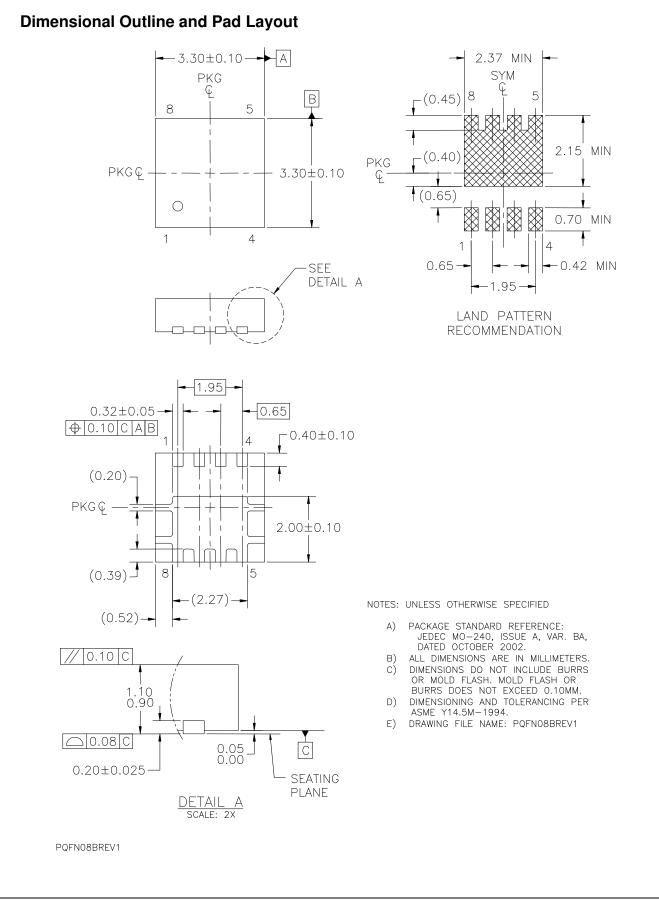
125 °C/W when mounted on a minimum pad of 2 oz copper











FDMC8321L N-Channel PowerTrench<sup>®</sup> MOSFET



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# FDMC8321L N-Channel PowerTrench<sup>®</sup> MOSFE<sup>-</sup>

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